OP265, OP266 Series (A, B, D, W)



#### **Features:**

- T-1 (3 mm) package style
- Choice of narrow or wide irradiance pattern
- · Choice of dome or flat lens
- Mechanically and spectrally matched to other OPTEK devices
- Higher power output than GaAs at equivalent drive currents
- 890 nm diodes



#### **Description:**

Each device in the **OP265** and **OP266** series is a high intensity gallium arsenide infrared emitting diode (GaAIAs) that is molded in an IR transmissive clear epoxy package with either a dome or flat lens. Devices feature narrow and wide irradiance patterns and a variety of electrical characteristics. The small T-1 package style makes these devices ideal for space-limited applications.

OP265 devices conform to the OP505 and OP535 series devices. OP266 devices conform to OP506 series devices.

Please refer to Application Bulletins 208 and 210 for additional design information and reliability (degradation) data.

## **Applications:**

- Space-limited applications
- · Applications requiring coupling efficiency
- Battery-operated or voltage-limited applications

Ordering Information									
Part LED Peak Number Wavelength		Output Power (mW/cm²) I <sub>F</sub> (mA) Min / Max Typ / Max		Total Beam Angle	Lead Length				
OP265A	890 nm	2.70 / NA		18°	See page 2				
OP265B		1.65 / 4.70	20 / 50						
OP265D		0.54 / NA							
OP265W		1.00 / NA		90°					
OP266A		2.70 / NA		18°					
OP266B		1.65 / 4.70							
OP266D		0.54 / NA							
OP266W		1.00 / NA		90°					

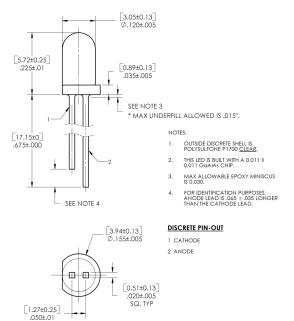


OP265, OP266 Series

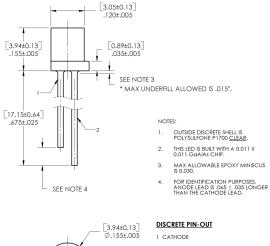
(A, B, D, W)



### **OP265 (A, B, D)**

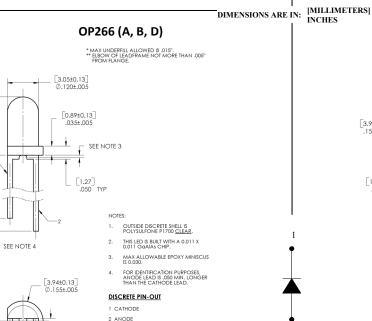


### **OP265W**



# П [0.51±0.13] .020±.005 SQ. TYP [1.27±0.25] .050±.01

2 ANODE



Pin# 1

2

Cathode

Anode

# **OP266W** \* MAX UNDERFILL ALLOWED IS .015". \*\* ELBOW OF LEADFRAME NOT MORE THAN .005" FROM FLANGE 3.05±0.13 [0.89±0.13] .035±.005 [3.94±0.13] SEE NOTE 2 [1.27] .050 TYP [12.70] .500 MIN OUTSIDE DISCRETE SHELL IS POLYSULFONE P1700 CLEAR. MAX ALLOWABLE EPOXY MINISCUS IS 0,030. SEE NOTE 3 DISCRETE PIN-OUT [3.94±0.13] Ø.155±.005 1 CATHODE 2 ANODE

[0.51±0.13] .020±.005 SQ. TYP

# CONTAINS POLYSULFONE

To avoid stress cracking, we suggest using ND Industries' Vibra-Tite for thread-locking. Vibra-Tite evaporates fast without causing structural failure in OPTEK'S molded plastics.

[0.51±0.13] .020±.005 SQ. TYP

### General Note

[2.54±0.25] .100±.01

5.72±0.25

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OP265, OP266 Series

(A, B, D, W)



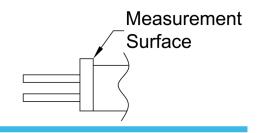
# **Electrical Specifications**

Absolute Maximum Ratings (T <sub>A</sub> = 25° C unless otherwise noted)					
Storage and Operating Temperature Range	-40° C to +100° C				
Reverse Voltage	2.0 V				
Continuous Forward Current	50 mA				
Peak Forward Current (1 μs pulse width, 300 pps)	3.0 A				
Lead Soldering Temperature [1/16 inch (1.6 mm) from case for 5 seconds with soldering iron]	260° C				
Power Dissipation	100 mW <sup>(1)</sup>				

Electrical	Electrical Characteristics (T <sub>A</sub> = 25° C unless otherwise noted)								
SYMBOL	PARAMETER		TYP	MAX	UNITS	TEST CONDITIONS			
Input Diode									
E <sub>E (APT)</sub>	Apertured Radiant Incidence OP265A, OP266A OP265B, OP266B OP265D, OP266D	2.70 1.65 0.54	- - -	- 4.70 -	mW/cm²	I <sub>F</sub> = 20 mA <sup>(2)</sup>			
P <sub>o</sub>	Radiant Power Output OP265, OP266 (A, B, D) OP265W, OP266W	- 1.00	-	- -	mW	I <sub>F</sub> = 20 mA			
V <sub>F</sub>	Forward Voltage	-	-	1.80	V	I <sub>F</sub> = 20 mA			
I <sub>R</sub>	Reverse Current		-	100	μΑ	V <sub>R</sub> = 2 V			
$\lambda_{P}$	Wavelength at Peak Emission	-	890	-	nm	I <sub>F</sub> = 10 mA			
В	Spectral Bandwidth between Half Power Points	-	80	-	nm	I <sub>F</sub> = 10 mA			
$\Delta\lambda_{P}/\Delta T$	Spectral Shift with Temperature OP265, OP266 (A, B, D) OP265W, OP266W		±0.30 ±0.18		nm/°C	I <sub>F</sub> = Constant			
$\theta_{\sf HP}$	Emission Angle at Half Power Points OP265, OP266 (A, B, D) OP265W, OP266W		18 90		Degree	I <sub>F</sub> = 20 mA			
t <sub>r</sub>	Output Rise Time	-	500	-	ns	I <sub>F(PK)</sub> =100 mA, PW=10 μs, D.C.=10.0%			
t <sub>f</sub>	Output Fall Time	-	250	-	ns	I <sub>F(PK)</sub> =100 mA, PW=10 μs, D.C.=10.0%			

#### Notes:

- 1. Derate linearly 1.33 mW/°C above 25°C
- 2.  $E_{E(APT)}$  is a measurement of the average apertured rediant incidence ipon a sensing area 0.081" (2.06 mm) in diameter, perpendicular to and centered on the mechanical axis of the lens, and 0.590" (14.99 mm) from the measurement surface.  $E_{E(APT)}$  is not necessarily uniform within the measured areas.



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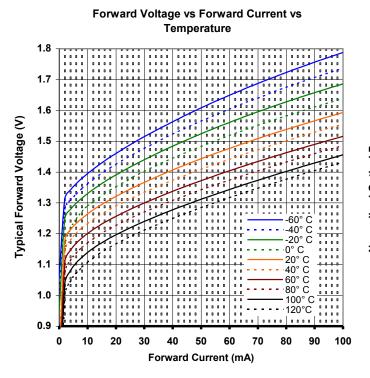
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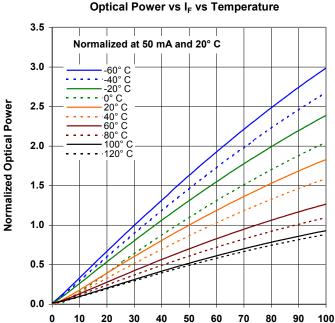
(A, B, D, W)



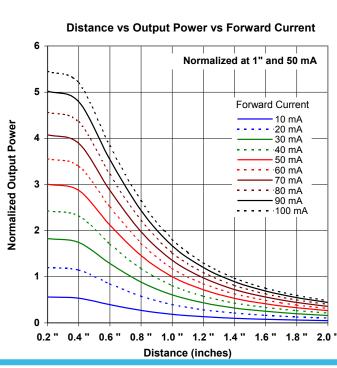
# **Performance**

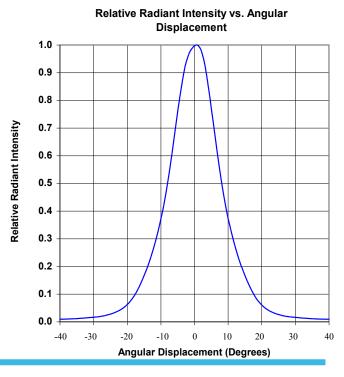
OP265, OP266 (A, B, D, W)





Forward Current I<sub>F</sub> (mA)





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